

# **QSI LASER DIODE**

## **SPECIFICATIONS FOR APPROVAL**

**Customer :**

**Model : QL85H6S-A/B/C**

### **Signature of Approval**

**Approved by** \_\_\_\_\_

**Checked by** \_\_\_\_\_

**Issued by** \_\_\_\_\_

### **Approval by Customer**



**QSI Co., Ltd.**

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**WWW.QSILaser.com**

# QL85H6S-A/B/C

AlGaAs Laser Diode

Quantum Semiconductor International Co., Ltd.

Ver.3 APR.2005

## ◆ OVERVIEW

QL85H6SA is a MOCVD grown 850nm band AlGaAs laser diode with quantum well structure. It's an attractive light source, with a typical light output power of 20mW for industrial optical module and sensor applications.

## ◆ APPLICATION

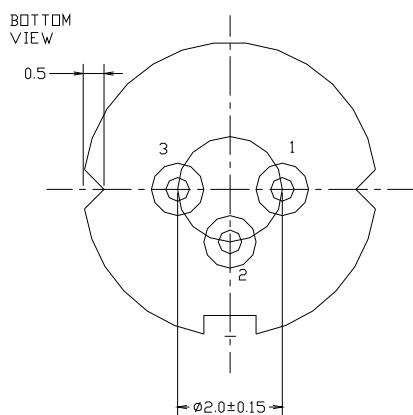
- Sensor
- Industrial Optical Module

## ◆ FEATURES

- Visible Light Output :  $\lambda_p = 850$  nm
- Optical Power Output : 20mW CW
- Package Type : TO-18 (5.6mm $\phi$ )
- Built-in Photo Diode for Monitoring Laser Diode

## ◆ ELECTRICAL CONNECTION

### Bottom View



### Pin Configuration

A	LD cathode, PD anode (Fig. 1)
B	LD , PD anode (Fig. 2)
C	LD anode, PD cathode (Fig. 3)

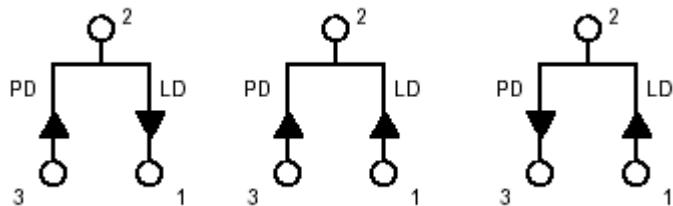


Fig. 1

QL85H6SA

Fig. 2

QL85H6SB

Fig. 3

QL85H6SC

## ◆ ABSOLUTE MAXIMUM RATING at Tc=25°C

Items	Symbols	Values	Unit
Optical Output Power	P	22	mW
Laser Diode Reverse Voltage	V	2	V
Photo Diode Reverse Voltage	V	30	V
Operating Temperature	Topr	-10 ~ +60	°C
Storage Temperature	Tstg	-40 ~ +85	°C

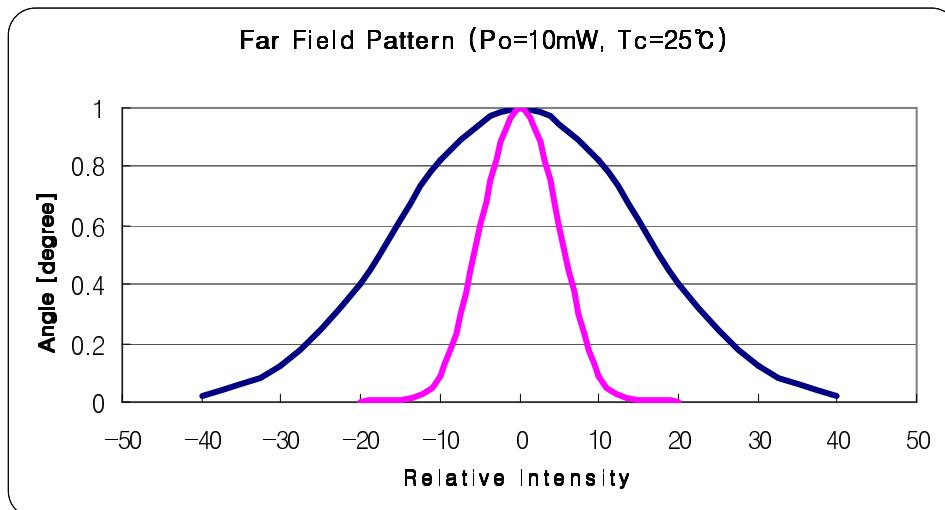
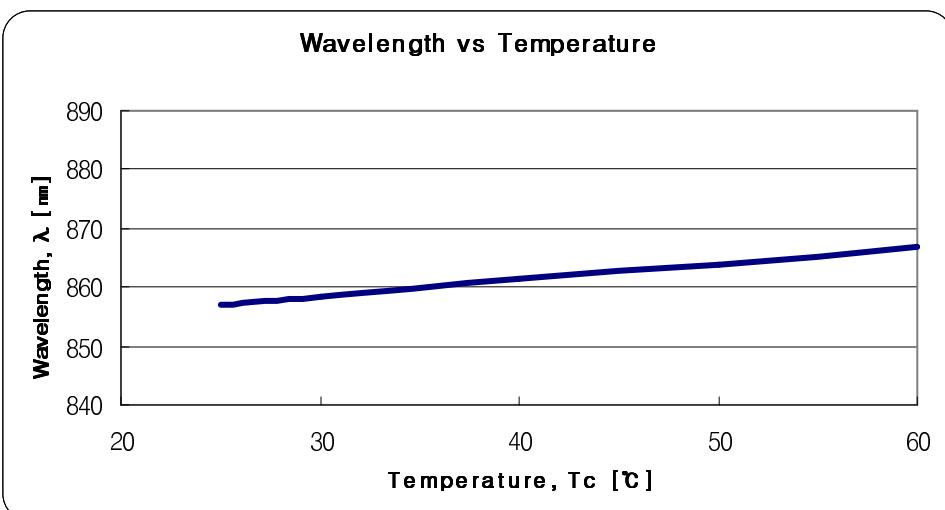
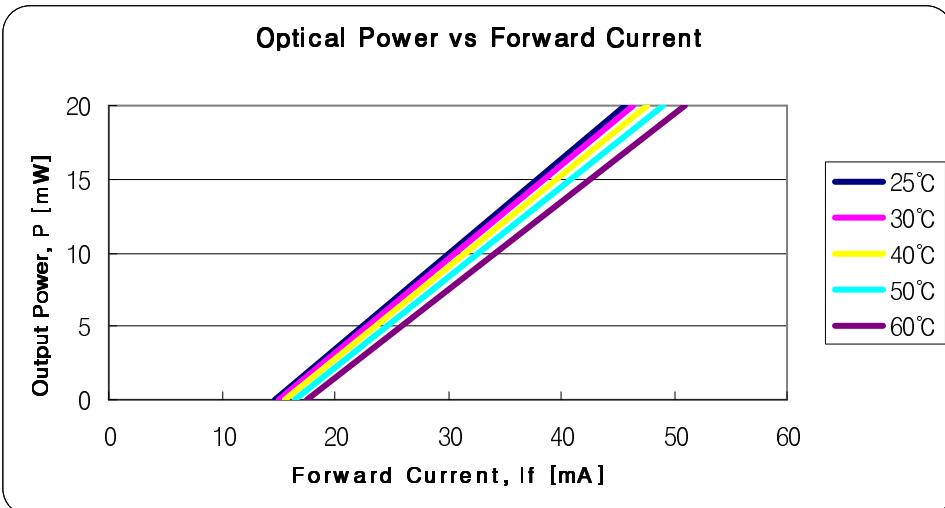
## ◆ ELECTRICAL and OPTICAL CHARACTERISTICS at Tc=25°C

Items	Symbols	Min.	Typ.	Max.	Unit	Condition
Optical Output Power	Po	-	20	-	mW	-
Threshold Current	Ith	5	20	35	mA	-
Operating Current	Iop	40	55	70	mA	Po=20mW
Slope Efficiency	SE	0.4	0.5	0.9	mW/mA	10~20 mW
Operating Voltage	Vop	-	2.0	2.5	V	Po=20mW
Lasing Wavelength	λp	845	855	865	nm	Po=20mW
Beam Divergence	θ	7	9	12	deg	Po=20mW
	θ ⊥	25	32	40	deg	Po=20mW
Beam Angle	Δθ	-	-	±2	deg	Po=20mW
	Δθ ⊥	-	-	±3	deg	Po=20mW
Monitor Current	Im	0.1	0.6	1.0	mA	Po=20mW
Astigmatism	As	-	-	15	μm	
Optical Distance	ΔX, ΔY, ΔZ	-	-	±60	μm	

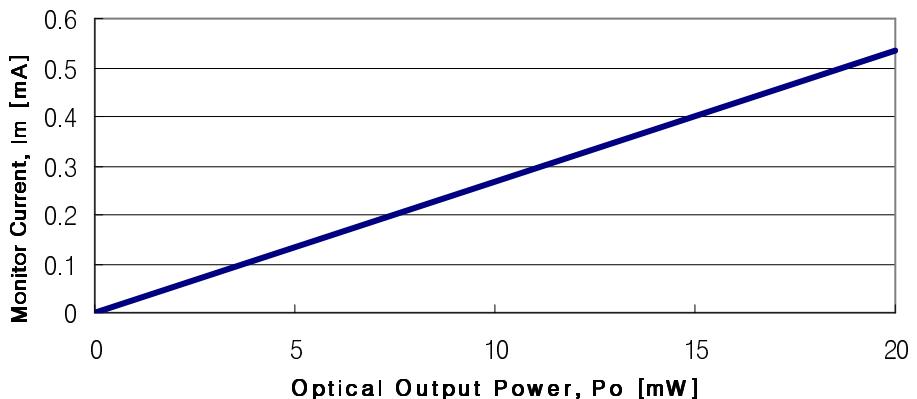
**NOTICE : QL85H6S-A/B/C to be operated on APC**

The above product specifications are subject to change without notice.

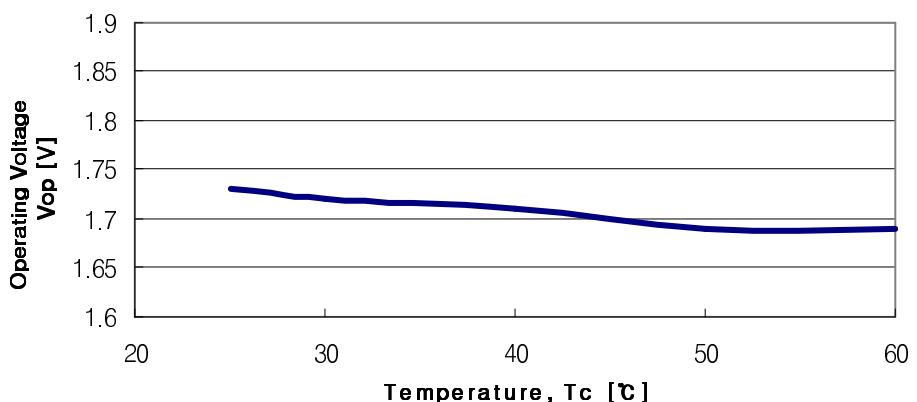
## EXAMPLE of REPRESENTITIVE CHARACTERISTICS



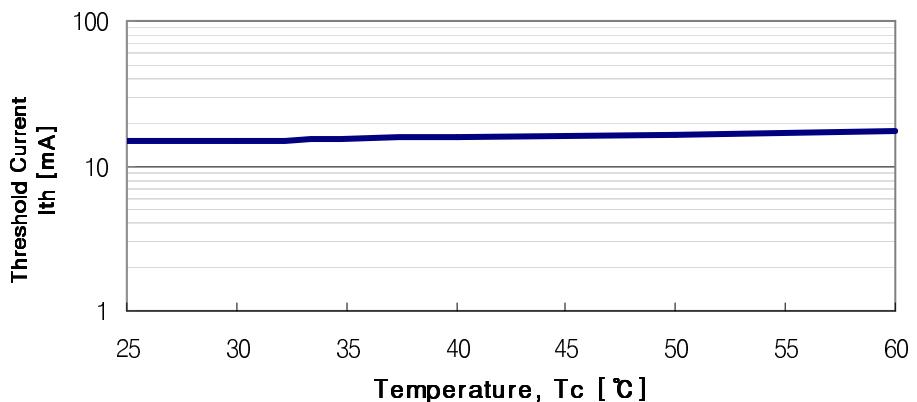
**Monitor Current vs Optical Power**



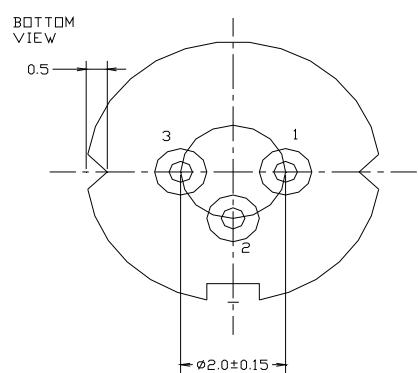
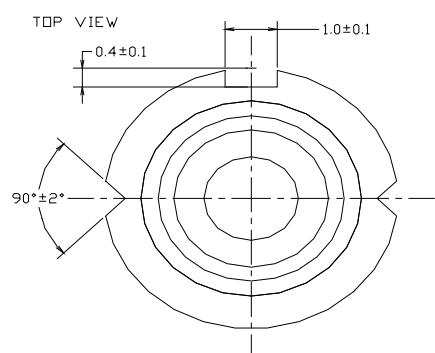
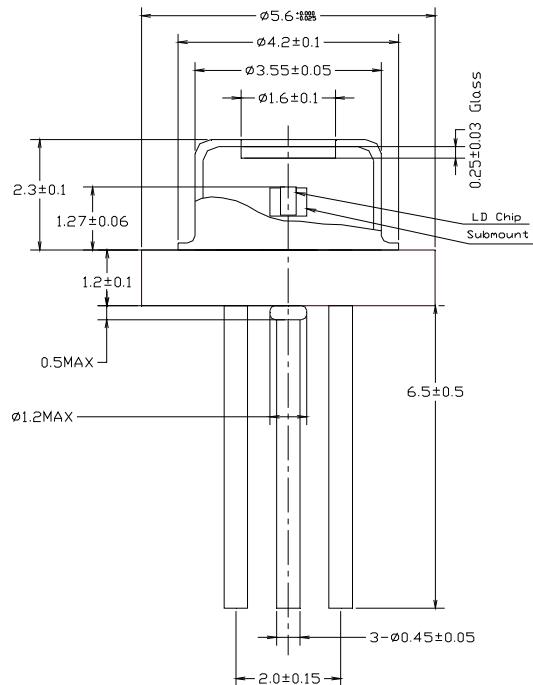
**Operating Voltage vs Temperature**



**Threshold Current vs Temperature**



## ◆ PACKAGE DIMENSION



## ◆PACKING

